Highly tunable time-reversal-invariant topological superconductivity in topological insulator thin films

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We study time-reversal-invariant topological superconductivity in topological insulator (TI) thin films with both intra- and inter-surface pairing. Nontrivial topology require either a π-phase difference between the intra-surface pairing states, spin-triplet inter-surface pairing, which is necessarily odd in the surface index, or spin-singlet inter-surface pairing with a sign-changing tunnel coupling, present in many TI thin films. In all cases the topological phase and its Kramers pair of Majorana edge modes is highly tunable with an applied electric field and varied chemical potential.

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Topology in condensed matter systems has received a massive amount of interest in recent years. Starting with the discovery of topological insulators (TIs) [1–4], where nontrivial topology of the bulk band structure creates surface states with a Dirac-spectrum crossing the bulk band gap, topology is now also applied widely in the discussion of properties of superconductors and semimetals [5–8]. In topological superconductors the zero-energy surface states are particularly intriguing as they are Majorana modes, due to their equal electron and hole characteristics [9–12]. The non-Abelian statistics of Majorana zero-modes makes topological superconductors very promising for topological quantum computation [13–15].

Many topological superconductors explicitly break time-reversal symmetry. This is usually achieved by magnetic field or impurities, which together with Rashba spin-orbit coupling and superconductivity can give nontrivial topology [16–23]. A close alternative is superconducting TI surfaces, where Majorana modes appear in vortex cores or at ferromagnetic interfaces, again requiring magnetic fields [24–28]. However, time-reversal-invariant superconductors can also be topologically nontrivial, where instead the surface spectrum consists of a Kramers pair of helical Majorana modes [29]. Despite the doubling of the Majorana modes, non-Abelian operations, suitable for quantum computation, have still been demonstrated in these systems [30]. Since superconductivity is generally very sensitive to magnetic fields, time-reversal-invariant systems have a very natural advantage in terms of stability of the superconducting phase.

Proposals for time-reversal-invariant superconductors have mainly been based on multi-channel systems, since noninteracting single-channel systems with conventional s-wave superconductivity cannot be topological [31]. For example, multiband/orbital systems and $s_{\pm}$-wave iron-based superconductors have been shown to be able to host a nontrivial phase [32–34]. Double wire systems with Rashba spin-orbit coupling have also been studied, where a π-phase difference of the superconducting order parameter between the two wires [35], or a strong inter-wire pairing [36–39] have been shown to give nontrivial topology. A π-phase difference has also been shown to give a nontrivial topology in a simple model for unbiased TI thin films [40]. Similar criteria have also been found in double layer Rashba materials with strong interactions [41]. However, all these systems have shown very limited tunability of the topological phase by experimentally controllable parameters, which both limit applications and possibilities to detect nontrivial topological phases.

In this Letter we study conventional s-wave superconductivity in realistic models of superconductivity in three-dimensional (3D) TI thin films. For TI films thinner than 6 quintuple layers (QL), an energy gap opens in the surface states [42]. However, sufficient doping produces a finite density of states at the Fermi level, such that thin films can easily enter a superconducting phase either by proximity to external superconductors [27, 43], or possibly by an intrinsic mechanism. To allow for the most general situation we consider both s-wave intra-surface pairing and inter-surface pairing, since inter-surface pairing is present in proximity-induced superconducting thin films through crossed Andreev reflection [44, 45] and proximity effect [46]. We show that intra-surface pairing leads to a topologically nontrivial state when there is a π-phase difference between the two surface pairing terms. Further, spin-triplet inter-surface pairing is odd in surface index and we show therefore also nontrivial. For nontrivial topology with spin-singlet inter-surface pairing, the thin film tunneling needs to change sign with momentum, which is very common in TI thin films. Most importantly, in all cases the topological phase is highly tunable with an applied electric field or by varying the chemical potential. This allows for direct tuning of time-reversal-invariant topological superconductivity and its associated Kramers pair of Majorana edge modes in TI thin films.

Figure 1 shows a schematic of the system under study. The TI thin film (green) is acting like a bilayer material with tunneling $t(k)$ between its two surfaces. We also allow for an electrostatic potential difference $2V$ be-

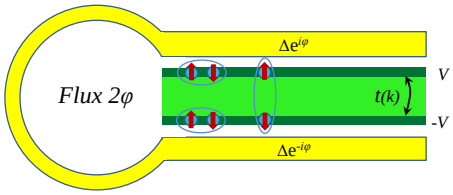

FIG. 1: (Color online.) Schematic setup for proximity-induced superconductivity in 3D TI thin films. Green area represents the TI thin film with its two surfaces (dark green), $t(k)$ the tunneling, and $2V$ an applied electrostatic potential. Yellow part is the s-wave superconductor, with the superconducting phase controlled by the magnetic flux 2φ. Depicted are also intra- (left) and inter-surface (right) Cooper pairs.

tween the two surfaces, which causes a structure inversion asymmetry. The effective low-energy Hamiltonian of the 3D TI thin film can be written as [47, 48]:

$$h(k) = \hbar v_F(\mathbf{k}\cdot\sigma)\otimes\tau_z + t(k)\sigma_0\otimes\tau_x + V\sigma_0\otimes\tau_z - \mu\sigma_0\otimes\tau_0. \quad (1)$$

Here $\mathbf{k} = (k_x, k_y)$ with $|\mathbf{k}| = k$ and v_F is the Fermi velocity, while σ and τ are Pauli matrices in spin and surface space, respectively. The inter-surface tunneling $t(k)$ in TI thin films is of the form $t_0 - t_1k^2$ [42]. Values for the intrinsic parameters for thin films of the prototypical TI Bi_2Se_3 are given in Table I. Due to a finite

	v_F (10^5 ms^{-1})	t_0 (eV)	t_1 (eVÅ^2)
2 QLs	4.71	0.125	21.8
3 QLs	4.81	0.069	18.0
4 QLs	4.48	0.035	10.0

TABLE I: Parameters in the Hamiltonian Eq. (1) for Bi_2Se_3 TI thin films, extracted by fitting the dispersion relation with ARPES data (adopted from Ref. [42]).

t_0, intrinsic Bi_2Se_3 thin films have a completely gapped spectrum. Finally, tunable parameters are both the electrostatic potential V, by applying an electric field as a gate voltage, and the chemical potential μ, which is adjustable by e.g. chemical doping. In order to achieve a sustainable superconducting state we assume a finite doping, such that the Fermi level is located inside the conduction band.

Superconductivity in TIs can be either intrinsic [49–57] or induced by proximity to an external superconductor [27, 43]. To allow for a general situation, we consider both Cooper pairs formed within each surface, intra-surface pairing Δ_1 and Δ_2, and between the two surfaces, inter-surface pairing Δ_{12}. By also assuming finite disorder, we limit ourselves to s-wave states. This results in the total order parameter in the surface basis being

$$\hat{\Delta} = \begin{pmatrix} \Delta_1 & \Delta^s_{12} + \Delta^t_{12} \\ \Delta^s_{12} - \Delta^t_{12} & \Delta_2 \end{pmatrix}, \quad (2)$$

where the intra-surface pairing is necessarily spin-singlet, while inter-surface pairing can be either spin-singlet (s) or triplet (t), depending on the parity in surface index being even or odd, respectively. Finally, the total BdG Hamiltonian of the system, written in Nambu space, is

$$H(k) = \begin{pmatrix} h(k) & \hat{\Delta} \\ \hat{\Delta}^\dagger & -h(-k)^T \end{pmatrix}. \quad (3)$$

Topological order.—For a time-reversal-invariant system we can rotate the BdG Hamiltonian in Eq. (3) and write it in the basis $(\Psi_k \mp i\hat{T}\Psi^\dagger_{-k})/\sqrt{2}$, where Ψ_k is the original normal-state basis. This results in

$$H(k) = \begin{pmatrix} 0 & h(k) + i\hat{T}\Delta^\dagger \\ h(k) - i\hat{T}\Delta^\dagger & 0 \end{pmatrix}, \quad (4)$$

where $\hat{T} = \tau_0 \otimes i\sigma_y\kappa$ is the time-reversal matrix, with κ the complex conjugation operator. Following Ref. [58] we now define the matrix element

$$\delta_n(k) = \langle\psi_n(k)|\hat{T}\Delta^\dagger|\psi_n(k)\rangle, \quad (5)$$

where $|\psi_n(k)\rangle$ is the wave function of the nth band of the normal state Hamiltonian $h(k)$. Applying this expression in the weak pairing limit in 2D, the topological order can be classified by the expression $N_{2D} = \Pi_n(\mathrm{sgn}(\delta_n))^{m_n}$, where m_n is the number of time-reversal-invariant points enclosed by the normal state Fermi surface(s) [58]. In the weak-pairing limit $\delta_n(k)$ is only non-zero close to the Fermi surface and for a fully-gapped superconductor it remains finite on all Fermi surfaces, making the sign of $\delta_n(k)$ a good topological number. For the TI thin film in Eq. (1), the Fermi surfaces are centered around $k = 0$ and never touch any Brillouin zone boundaries, resulting in $m_n = 1$. After some calculations we also obtain the normalized wave functions corresponding to the two bands crossing the Fermi surface as

$$|\psi_n\rangle^T = \frac{1}{\sqrt{2}}\left(\cos(\tfrac{\theta_n}{2}), n\cos(\tfrac{\theta_n}{2})e^{i\phi_k}, \sin(\tfrac{\theta_n}{2}), n\sin(\tfrac{\theta_n}{2})e^{i\phi_k}\right),$$

where $n = \pm 1$ indicates the two different conduction bands and ϕ_k is the polar angle of the momentum. We have also defined the new variable θ_n, such that $\sin(\theta_n) = t(k)/\sqrt{(k+nV)^2 + t(k)^2}$. Using the above wave functions, together with Eqs. (2) and (5), we arrive at

$$\delta_n = \frac{\cos^2(\frac{\theta_n}{2})}{2}[\Delta_1 + \Delta_2\tan^2(\frac{\theta_n}{2}) + 2\Delta^s_{12}\tan(\frac{\theta_n}{2})] \quad (6)$$

for a spin-singlet s-wave superconducting state in a TI thin film. The spin-triplet inter-surface pairing is absent in this expression since it is odd under the surface index and thus give a zero contribution in Eq. (5).

Intra-surface pairing.—We first consider the case of zero or negligible inter-surface pairing and focus on only

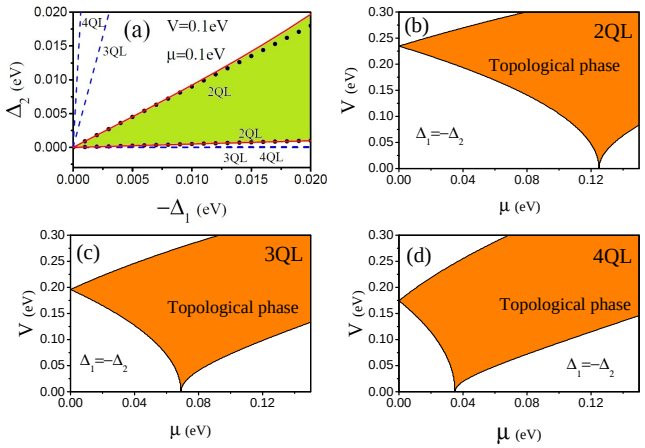

FIG. 2: (Color online.) Topological phase diagram for Bi_2Se_3 TI thin films for finite intra-surface pairing in the plane of (a) $(-\Delta_1, \Delta_2)$ and (b-d) (V, μ). In (a) dashed (3, 4 QLs) and dotted (2 QLs) lines display the topological criterion based on δ_n in Eq. (6), while solid red lines show the gap closing for the full Hamiltonian Eq. (3) for 2 QLs. Here $\mu = 0.1$ eV and $V = 0.1$ eV. In (b-d) $\Delta_1 = -\Delta_2$ for 2-4 QL thick films with nontrivial phase in orange.

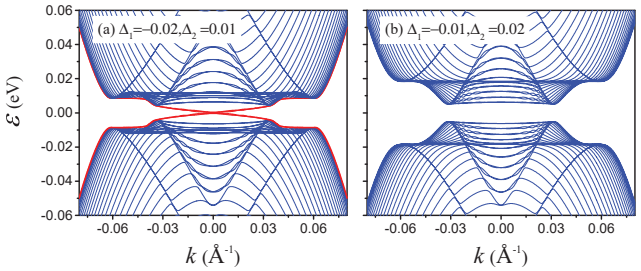

FIG. 3: (Color online.) Band dispersion of a bilayer Rashba nanoribbon, representing the Hamiltonian Eq. (3) of a 2 QL Bi_2Se_3 thin film for $V = \mu = 0.1$ eV and (a) $\Delta_1 = -0.02$ eV, $\Delta_2 = 0.01$ eV, (b) $\Delta_1 = -0.01$ eV, $\Delta_2 = 0.02$ eV with bulk states (blue) and edge states (red).

finite intra-surface orders Δ_i. We assume that Δ_i is either produced by an intrinsic mechanism or by proximity effect to a conventional superconductor, in both cases resulting in spin-singlet s-wave symmetry. The setup in Fig. 1 for proximity-induced superconductivity allows for separately tuning the superconducting phases induced in the two surfaces of the TI thin film by controlling the magnetic flux. The two order parameter amplitudes can also be different by modifying the coupling between the TI thin film and the superconductor. From Eq. (6) it is clear that if the superconducting orders have the same sign, $\Delta_1\Delta_2 > 0$, then δ_n always has the same sign for all bands. Thus, there exists no nontrivial topological phase if there is no phase difference between the superconducting states in the two surfaces. Limiting ourselves to time-reversal-invariant superconductivity, a π-shift is also possible between the two superconducting states. For the situation $\Delta_1\Delta_2 < 0$, the quantity $\tan^2(\theta_n/2)$ must be smaller than $(-\Delta_1/\Delta_2)$ on one of the Fermi surfaces but larger than it on the other in order to realize nontrivial topology. This means that the topological phase occurs between the two lines $\Delta_1 = -\tan^2(\theta_\pm/2)\Delta_2$.

Figure 2(a) shows the nontrivial topological phase for thin films of Bi_2Se_3 in the plane of $(-\Delta_1, \Delta_2)$ for $V = \mu = 0.1$eV in the absence of any inter-surface pairing. Dashed/dotted lines show the condition $\Delta_1 = -\Delta_2 \tan^2(\theta_\pm/2)$ for thin films with thicknesses 2-4 QLs. Note how the topological phase grows with increasing film thickness. At the topological phase transition between the trivial and nontrivial phases the quasiparticle energy spectrum necessarily closes. The solid red lines in Fig. 2(a) show the energy gap closing for the Hamiltonian Eq. (3) for a 2 QL Bi_2Se_3 thin film, with the green area marking the topological nontrivial phase. The gap closing exactly coincides with the boundary of the topological region determined by the signs of δ_n for small values of Δ_i, but there are small deviations for stronger superconductivity. This is not surprising since the topological criterion based on δ_n is strictly speaking only valid in the weak-pairing limit as it uses the normal state wave functions. In Fig. 2 (b-d) we investigate how the topological region (orange) varies with the tunable parameters of a TI thin film, the chemical potential μ and electric potential V, for a π-phase difference between the two superconductors proximitized to the TI thin film. As seen, a large part of the phase diagram is in the nontrivial topological phase for 2-4 QLs films. The nontrivial phase is even reachable for $\mu = 0$ or $V = 0$, although much less fine-tuning is needed when applying an electric field to films with finite doping. This shows that it is easy to both achieve a time-reversal-invariant nontrivial topological state in TI thin films, and, most importantly, the topology is highly tunable by applying an electric field.

To illustrate that the nontrivial topological state hosts edge states we also calculate the band dispersion for an infinite (in the direction perpendicular to the edge) nanoribbon of a bilayer Rashba material on a square lattice with parameters such that the normal state Hamiltonian represents Eq. (1) for a 2 QL Bi_2Se_3 TI thin film. In Fig. 3(a) we plot the band dispersion for $\Delta_1 = -0.02$ eV, $\Delta_2 = 0.01$ eV and $V = \mu = 0.1$ eV, which is well within the topological phase according to Fig. 2(a). There is a Kramers pair of Majorana modes (red lines) crossing the bulk superconducting gap, which are very well localized to the edges of the nanoribbon. This confirms the nontrivial topology of the system. In Fig. 3(b) we instead plot the band dispersion for $\Delta_1 = -0.01$ eV and $\Delta_2 = 0.02$ eV where the topology is trivial according to Fig. 2(a) and confirmed by the fully gapped spectrum.

Inter-surface spin-singlet pairing.—Next we also al-

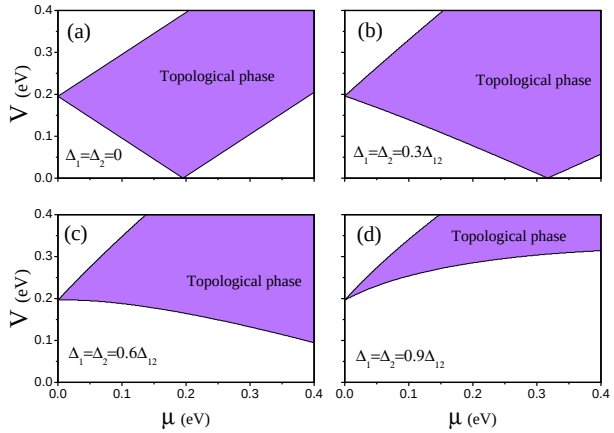

FIG. 4: (Color online.) Topological phase diagram for a 3 QL Bi_2Se_3 TI thin film for finite spin-singlet inter-surface pairing in the plane of (V, μ) when (a) $\Delta_1 = \Delta_2 = 0$, (b) $\Delta_1\Delta_2 = 0.3\Delta_{12}^s$, (c) $\Delta_1 = \Delta_2 = 0.6\Delta_{12}^s$, and (d) $\Delta_1 = \Delta_2 = 0.9\Delta_{12}^s$.

low for inter-surface spin-singlet pairing. For proximity-induced superconductivity in thin films inter-surface pairing can be strong, especially when generated by crossed Andreev reflection [44, 45]. In this process the Cooper pair is split between the two surfaces, which is possible when the superconducting penetration depth is larger than the thin film thickness. Here we restrict the discussion to the same sign for Δ_1, Δ_2, and Δ_{12}^s, which is the simplest proximity-induced setup [63]. Under this condition the sign of $\tan(\theta_n/2) = [\sqrt{(k+nV)^2 + t(k)^2} - (k+nV)]/t(k)$ is decisive in determining the sign of δ_n in Eq. (6). As a direct consequence, nontrivial topology is only possible if $t(k)$ is negative for at least one band. In addition, for positive and equal intra-surface pairing $\Delta_1 = \Delta_2$, as expected in e.g. the setup in Fig. 1, the inter-surface pairing needs to fullfil $\Delta_{12}^s > \Delta_1 = \Delta_2$ in order to reach a nontrivial state. This latter condition is often fulfilled in systems with strong electron-electron interactions, where the repulsive interaction heavily suppresses intra-surface pairing, while inter-surface pairing is significantly less affected [59–61]. Near the limit $\Delta_i = 0$, achievable for strong enough interactions, the sign of δ_n is simply equal to the sign of $t(k)$ on each Fermi surface.

In Fig. 4 we plot the topological phase of a 3 QL Bi_2Se_3 thin film for finite inter-surface pairing with different intra-surface contributions as function of the two tunable parameters V and μ. As the intra-surface pairing approach the inter-surface pairing, the nontrivial topological region (purple) shrinks, but a large nontrivial region is present even for substantially large intra-surface pairing amplitudes. The clear dependence on the size of the inter-surface pairing is somewhat reminiscent to a 1D double Rashba wire system, where topological superconductivity has been found for a negative determinant of the pairing matrix in wire space [36]. However, for TI thin film systems the topology is also very sensitive to the sign of the tunneling function $t(k)$ on each Fermi surface, which in turn is highly dependent on both the chemical doping μ and electric potential V. This leads to the topology being easily controllable for TI thin films.

Inter-surface spin-triplet pairing.—A finite spin-triplet inter-surface pairing Δ_{12}^t gives zero contribution to Eq. (5) since it is odd under the surface index, and cannot be investigated within the above framework. Instead, we make use of an analysis of the bulk superconducting state in Cu-doped Bi_2Se_3, which is one of the most studied superconducting TIs [49–57]. Using the lattice symmetries of the centrosymmetric bulk Bi_2Se_3, the superconducting pair amplitudes in $Cu_xBi_2Se_3$ have been analyzed in terms of the orbital structure, divided into intra-orbital spin-singlet and inter-orbital spin-singlet and triplet states [56, 57]. It was shown that a fully gapped time-reversal-invariant topological superconducting state exists in this centrosymmetric material for an odd inter-orbital order parameter, which is necessarily in a spin-triplet state [56].

We expect that the thin film limit of $Cu_xBi_2Se_3$ is given by the Hamiltonian Eq. (1) with a doping-induced shift in the chemical potential, since the bulk band dispersion has experimentally been shown to not vary significantly with Cu-doping [49, 50]. Moreover, the upper surface of a TI thin film is almost exclusively composed of one orbital, while the states on the opposite surface come from the other orbital [62]. Thus, we can generalize the bulk results based on orbital parity [56] and apply them to the surface parity of a TI thin film. Using this argument, we find a fully gapped nontrivial topological phase for finite odd inter-surface spin-triplet superconducting pairing Δ_{12}^t in a TI thin film. Applying an electrostatic potential V breaks the structure inversion symmetry, which invalidates the above proof of a nontrivial topological state. However, by numerically studying the energy dispersion of TI thin film nano-ribbons, we find that the topologically protected zero-energy edge states prevail to moderately high V, but that the topology becomes trivial above a critical V.

Summary.—We have investigated the possibilities for time-reversal-invariant topological superconductivity in 3D TI thin films. We show that pure intra-surface pairing often lead to topological superconductivity if the order parameters have different signs on the two different surfaces. Topologically nontrivial spin-singlet inter-surface pairing requires the inter-surface tunneling to change sign with momentum, a feature very special to TI thin films, while spin-triplet inter-surface pairing is odd in surface index and therefore prone to be nontrivial. In all cases, the topology is highly dependent on the applied electric field and chemical potential, which opens for exciting prospects of *in-situ* tuning of time-reversal invariant topological superconductivity and its associated Kramers pair of Majorana edge modes in TI thin films.

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